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SIDDHARTH INSTITUTE OF ENGINEERING & TECHNOLOGY:: PUTTUR
(AUTONOMOUS)

B.Tech II Year I Semester Regular & Supplementary Examinations March-2023

ELECTRONIC DEVICES AND CIRCUITS

(Electronics and Communication Engineering)

Time: 3 hours

Max. Marks: 60

(Answer all Five Units 5 x 12 = 60 Marks)

UNIT-I

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|---|--|-----|----|----|
| 1 | a Analyze the current components of a PN Junction Diode and derive the diode current equation. | CO2 | L4 | 6M |
| | b A PN junction germanium diode has a reverse saturation current of $10 \mu\text{A}$ at the room temperature of 27°C . It is observed to be $30 \mu\text{A}$, when the room temperature is increased. Calculate the new room temperature. | CO2 | L3 | 6M |

OR

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|---|--|-----|----|----|
| 2 | a Define Zener Diode and Show that the Zener Diode can act as a voltage regulator with a neat circuit diagram. | CO4 | L2 | 6M |
| | b Sketch and explain the V-I characteristics of Zener Diode and mention its application. | CO3 | L3 | 6M |

UNIT-II

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|---|---|-----|----|----|
| 3 | a Classify and Explain different types of LCD based on construction. List the advantages and applications of LCD. | CO1 | L2 | 6M |
| | b Explain the construction, working and applications of Solar Cell. | CO3 | L2 | 6M |

OR

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|---|--|-----|----|----|
| 4 | a Demonstrate the working principle of LC filter with neat circuit diagram and derive the expression for its ripple factor. List its advantages and disadvantages. | CO3 | L4 | 6M |
| | b Draw the circuit symbol of UJT and its characteristics with neat diagram and list its applications. | CO1 | L1 | 6M |

UNIT-III

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|---|---|-----|----|----|
| 5 | a Explain the construction of NPN transistor with a neat diagram. | CO1 | L2 | 6M |
| | b If the base current in a transistor is $20 \mu\text{A}$ when the emitter current is 6.4mA , what are the values of α and β ? Also calculate the collector current. | CO2 | L2 | 6M |

OR

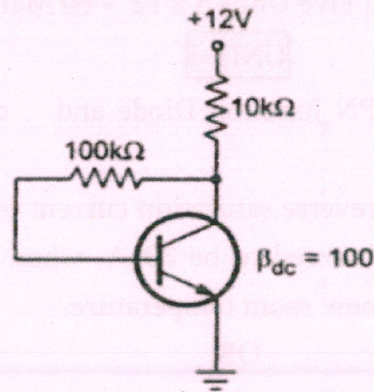
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|---|---|-----|----|----|
| 6 | a Explain the operation of N-Channel depletion type MOSFET with a neat diagram. | CO3 | L2 | 6M |
| | b Compare the performance of JFET with MOSFET. | CO1 | L1 | 6M |

UNIT-IV

- 7 a Define Transistor biasing Derive the expression for Stability Factor, Sf. from Collector current equation. CO3 L4 6M
- b Explain the concept of DC and AC Load lines and discuss the criteria for fixing the Q-point. CO3 L2 6M

OR

- 8 a Define and Explain Thermal Runaway and Thermal Resistance. CO2 L2 6M
- b Determine the Q-point for the circuit shown in the Figure. CO6 L3 6M



UNIT-V

- 9 a With neat diagram, summarize the parameters of CE amplifier using approximate analysis. CO5 L2 6M
- b Examine the expressions for current gain, voltage gain, input hybrid model. CO5 L2 6M

OR

- 10 a Draw the circuit diagram of JFET Common Source amplifier with voltage divider bias for bypassed R_s and determine the expression for input impedance, output impedance and voltage gain. CO5 L3 6M
- b Summarize the expressions for input impedance, output impedance and voltage gain of JFET Common Drain amplifier with neat diagram. CO5 L2 6M

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